Electronic Supplementary Information

Change Storage Mechanisms of Electrospun Mn₃O₄ Nanofibres for Highperformance Supercapacitors

Phansiri Suktha^{a,b}, Nutthaphon Phattharasupakun^a, Peerapan Dittanet^b and Montree Sawangphruk^{a,*}

^aDepartment of Chemical and Biomolecular Engineering, School of Energy Science and Engineering, Vidyasirimedhi Institute of Science and Technology, Rayong 21210, Thailand

^bThe Center of Excellence on Petrochemical and Materials Technology, Department of Chemical Engineering, Faculty of Engineering and NANOTEC Center for Nanoscale Materials Design for Green Nanotechnology and Center for Advanced Studies in Nanotechnology and its Applications in Chemical, Food and Agricultural Industries, Kasetsart University, Thailand.

* Corresponding author. Tel: 66(0)33-01-4251. Fax: 66(0)33-01-4445. E-mail address: montree.s@vistec.ac.th (M. Sawangphruk).

1. Calculations

1.1 Half-cell electrodes

The specific and areal capacitances of MnO_x half-cell electrodes can be calculated using equations (S1) and (S2)¹;

$$C_{sp}(F/g) = \frac{I x \Delta t}{\Delta V x m}$$
 (S1)

$$C_{\text{Areal}}(\text{mF/cm}^2) = \frac{\text{I x } \Delta t}{\Delta \text{V x S}}$$
(S2)

where C_{sp} is the specific capacitance (F/g), C_{Areal} is the areal capacitance (F/cm²), I is current, Δt is the discharging time, ΔV is the potential window, m is the mass of active material, and S is a geometrical area of electrode.

1.2 Full-cell supercapacitors

The specific capacitance of the Mn_3O_4 electrode can be calculated from the specific capacitance of the supercapacitor device by the equation (S3);

$$C_{\rm sp, \, CV} = 4 \frac{Q}{\Delta V \cdot m}$$
(S3)

where $C_{sp, CV}$ is a specific capacitance determined from CV (F g⁻¹), Q is an average charge in the discharged process (Coulomb, C) of the device, and m is the total mass of active material (g) of the device.

The specific and areal capacitances as a function of applied currents can be calculated from equations (S4) and (S5), respectively²;

$$C_{sp}(F/g) = 4 \frac{I x \Delta t}{\Delta V x m}$$
 (S4)

$$C_{Areal}(mF/cm^2) = 4 \frac{I x \Delta t}{\Delta V x S}$$
 (S5)

The specific energy and maximum specific power can be calculated by the equations (S6) and (S7) from the GCD measurement¹.

Specific Energy (E)
$$=\frac{1}{2}C_{cell}\Delta V^2$$
 (S6)

Maximum Specific Power (P_{max}) =
$$\frac{V_0^2}{4R_{cell}}$$
 (S7)

where C_{cell} is the cell capacitance, V_0 is an initial voltage of the cell, and R_{cell} is the cell's resistance.

1.3 X-ray absorption spectroscopy

The average oxidation numbers of Mn at the positive and negative electrodes calculated by following equation (S8)³ are 2.61 and 2.38, respectively.

< Mn oxidation state > =
$$\frac{3x\Delta E \text{ of the sample}}{\Delta E \text{ of } \text{Mn}^{2+} \text{ and } \text{Mn}^{3+}} - \left[2x\left(1 - \frac{\Delta E \text{ of the sample}}{\Delta E \text{ of } \text{Mn}^{2+} \text{ and } \text{Mn}^{3+}}\right)\right]$$
 (S8)

1.4 EQCM

The relationship of quartz resonance frequency (Δf) and mass change (Δm) follows Sauerbrey's equation (S9)⁴;

$$\Delta m = -C_{f} \Delta F \tag{S9}$$

where C_f is the calibration constant (0.0815 Hz ng⁻¹ cm⁻²)

2. XRD



Fig.S1 XRD of MnOx electrospun at 36 wt.% Mn(OAc)₂ in PAN after calcined at 500 °C and 1100 °C.

3. XAS calibration curve



Fig.S2 *Ex situ* high-resolution XAS calibration curve of the manganese oxide compared with the Mn standard compounds including Mn foil, MnO, Mn_2O_3 , and Mn_3O_4 .

4. Mass ratio by CV



Fig. S3 CV curve of Mn_3O_4 nanofibres in 0.5 M Na_2SO_4 at a scan rate of 50 mV s⁻¹

Positive electrode (Mn3O4 nanofibers).

 $C^+ = 68.65 \text{ F/g}$

V⁺ = 0.76 V

Negative electrode (N-rGO aerogel)

CV curves of N-rGO aerogel were previously reported by our group elsewhere ⁵.

C⁻ = 294.95 F/g

V⁻ = 0.54 V

 $\frac{m^+}{m^-} = \frac{(294.95)(0.54)}{(68.65)(0.76)} = 3.04$

Table S1. Ex situ high-resolution XAS results of the manganese oxide including MnO, Mn_2O_3 , and Mn_3O_4

Sample	E(eV)	ΔE(eV)	Oxidation number
MnO std.	6544.17	0	2
Mn ₂ O ₃ std.	6548.61	4.44	3
Bare Mn_3O_4	6547.15	2.98	2.67
Mn ₃ O ₄ 1 st charge (-)	6546.80	2.63	2.35
$Mn_3O_4 1^{st}$ charge (+)	6547.60	3.43	2.61
Mn ₃ O ₄ 1 st discharge (-)	6547.39	3.22	2.53
$Mn_3O_4 1^{st}$ discharge (+)	6547.58	3.41	2.51
$Mn_3O_4 2000^{th}$ charge (-)	6546.69	2.52	2.38
Mn_3O_4 2000 th charge (+)	6546.77	2.60	2.44

REFERENCES

- P. Suktha, P. Chiochan, P. lamprasertkun, J. Wutthiprom, N. Phattharasupakun, M. Suksomboon, T. Kaewsongpol, P. Sirisinudomkit, T. Pettong and M. Sawangphruk, *Electrochim. Acta*, 2015, **176**, 504-513.
- J. Cao, Y. Wang, Y. Zhou, D. Jia, J.-H. Ouyang and L. Guo, *J. Electroanal. Chem.*, 2012, 682, 23-28.
- 3. S. Daengsakul, P. Kidkhunthod, O. Soisang, T. Kuenoon, A. Bootchanont and S. Maensiri, *Microelectron. Eng.*, 2015, **146**, 38-42.
- 4. W.-Y. Tsai, P.-L. Taberna and P. Simon, J. Am. Chem. Soc., 2014, **136**, 8722-8728.
- P. lamprasertkun, A. Krittayavathananon and M. Sawangphruk, *Carbon*, 2016, **102**, 455-461.